

Features :

- Isolated mounting base 3000V~
- Pressure contact technology with
Increased power cycling capability
- Space and weight saving

Typical Applications

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

| V_{DSM}, V_{RSM} | V_{DRM}, V_{RRM} | 品名 |
|--------------------|--------------------|-----------|
| 2100V | 2000V | Mx500T200 |
| 2300V | 2200V | Mx500T220 |
| 2600V | 2500V | Mx500T250 |

| SYMBOL | CHARACTERISTIC | TEST CONDITIONS | $T_j(^{\circ}\text{C})$ | VALUE | | | UNIT |
|------------------------|--|--|-------------------------|-------|------|------|----------------------------------|
| | | | | Min. | Typ. | Max. | |
| $I_{T(AV)}$ | Mean on-state current | 180° half sine wave 50Hz Single side cooled, $T_c=85^{\circ}\text{C}$ | 125 | | | 500 | A |
| $I_{T(RMS)}$ | RMS on-state current | | | | | 785 | A |
| I_{DRM} I_{RRM} | Repetitive peak current | at V_{DRM} at V_{RRM} | 125 | | | 45 | mA |
| I_{TSM} | Surge on-state current | 10ms half sine wave $V_R=60\%V_{RRM}$ | 125 | | | 14.5 | kA |
| I^2t | I^2t for fusing coordination | | | | | 1051 | $\text{A}^2\text{s} \times 10^3$ |
| V_{TO} | Threshold voltage | | 125 | | | 0.85 | V |
| r_T | On-state slope resistance | | | | | 0.39 | m Ω |
| V_{TM} | Peak on-state voltage | $I_{TM}=1500\text{A}$ | 25 | | | 2.20 | V |
| dv/dt | Critical rate of rise of off-state voltage | $V_{DM}=67\%V_{DRM}$ | 125 | | | 1000 | V/ μs |
| di/dt | Critical rate of rise of on-state current | Gate source 1.5A $t_r \leq 0.5\mu\text{s}$ Repetitive | 125 | | | 200 | A/ μs |
| I_{GT} | Gate trigger current | $V_A=12\text{V}, I_A=1\text{A}$ | 25 | 30 | | 200 | mA |
| V_{GT} | Gate trigger voltage | | | 1.0 | | 3.0 | V |
| I_H | Holding current | | | 20 | | 200 | mA |
| V_{GD} | Non-trigger gate voltage | $V_{DM}=67\%V_{DRM}$ | 125 | 0.2 | | | V |
| $R_{th(j-c)}$ | Thermal resistance Junction to case | D.C. Single side cooled per chip | | | | 0.06 | $^{\circ}\text{C}/\text{W}$ |
| $R_{th(c-h)}$ | Thermal resistance case to heat sink | D.C. Single side cooled per chip | | | | 0.04 | $^{\circ}\text{C}/\text{W}$ |
| V_{iso} | Isolation voltage | 50Hz, R.M.S, $t=1\text{min}, I_{iso}: 1\text{mA}(\text{MAX})$ | | 3000 | | | V |
| F_m | Terminal connection torque (M10) | | | | 12.0 | | N·m |
| | Mounting torque (M6) | | | | 6.0 | | N·m |
| T_{vj} | Junction temperature | | | -40 | | 125 | $^{\circ}\text{C}$ |
| T_{stg} | Stored temperature | | | -40 | | 125 | $^{\circ}\text{C}$ |
| W_t | Weight | | | 1500 | | | g |
| Outline | M06 | | | | | | |

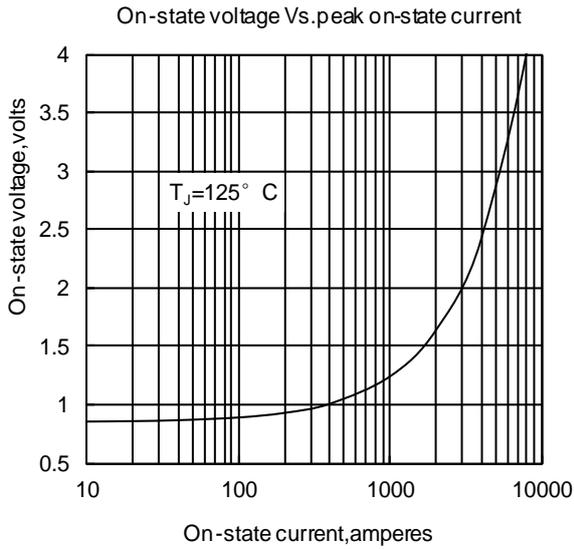


Fig. 1

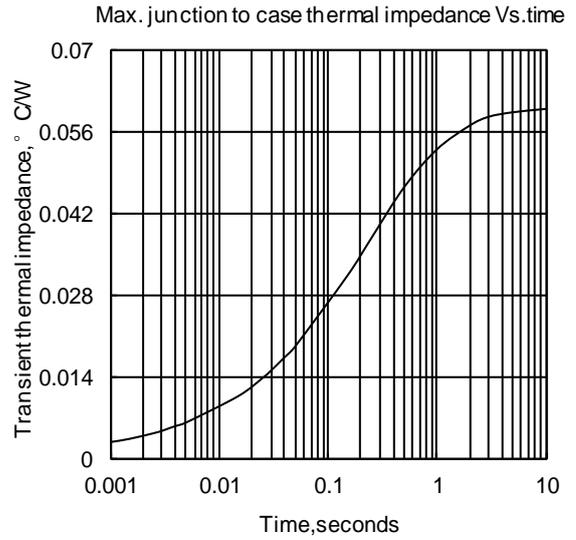


Fig. 2

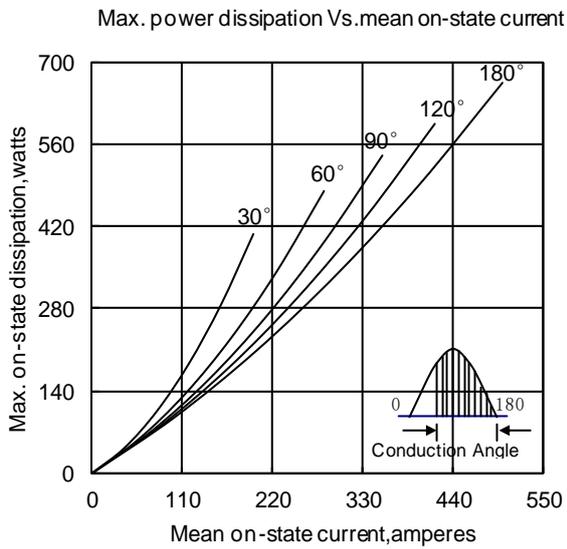


Fig. 3

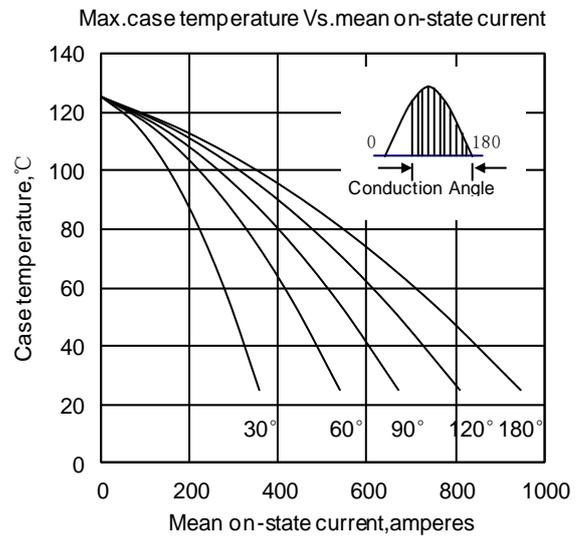


Fig. 4

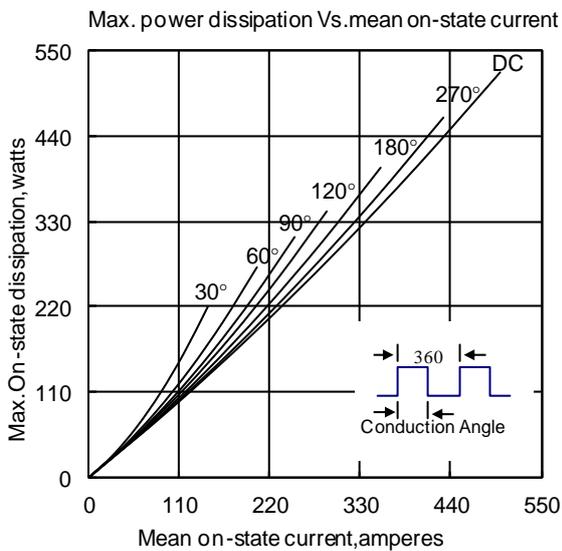


Fig. 5

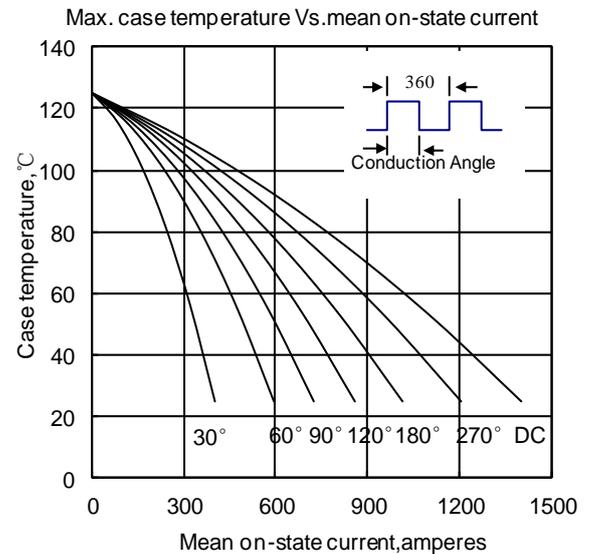


Fig. 6

